imall

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MMBTA55 / MMBTA56

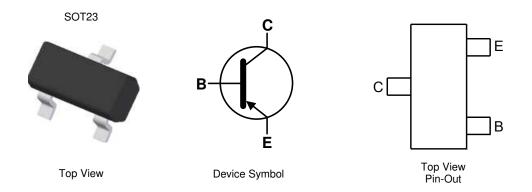
PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Complementary NPN Type: MMBTA05 / MMBTA06
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)



Ordering Information (Notes 4 & 5)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|------------|---------|--------------------|-----------------|-------------------|
| MMBTA55-7-F | AEC-Q101 | K2G | 7 | 8 | 3,000 |
| MMBTA56-7-F | AEC-Q101 | K2G | 7 | 8 | 3,000 |
| MMBTA56Q-7-F | Automotive | K2G | 7 | 8 | 3,000 |
| MMBTA56Q-13-F | Automotive | K2G | 13 | 8 | 10,000 |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

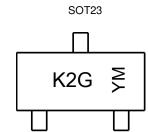
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

 Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} \mathsf{K2G} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex: C} = 2015) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex: 9} = \mathsf{September}) \end{array}$

Date Code Key

| Balo boad hoy | | | | | | | | | | | | |
|---------------|------|------|------|------|------|------|------|------|------|------|------|------|
| Year | 2015 | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 |
| Code | С | D | E | F | G | Н | | J | K | L | М | Ν |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | MMBTA55 | MMBTA56 | Unit |
|--------------------------------|------------------|---------|---------|------|
| Collector-Base Voltage | V _{CBO} | -60 | -80 | V |
| Collector-Emitter Voltage | V _{CEO} | -60 | -80 | V |
| Emitter-Base Voltage | V _{EBO} | -4 | .0 | V |
| Collector Current - Continuous | Ι _C | -5 | 00 | mA |

Thermal Characteristics (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|----------|------------------|-------------|-------|
| Dower Dissinction | (Note 6) | D | 310 | mW |
| Power Dissipation | (Note 7) | PD | 350 | IIIVV |
| Thermal Resistance, Junction to Ambient | (Note 6) | D | 403 | °C/W |
| Thermal Resistance, Junction to Ambient | (Note 7) | R _{0JA} | 357 | °C/W |
| Thermal Resistance, Junction to Leads (Note 8) | | R _{θJL} | 350 | °C/W |
| Operating and Storage Temperature Range | | TJ,TSTG | -55 to +150 | °C |

ESD Ratings (Note 9)

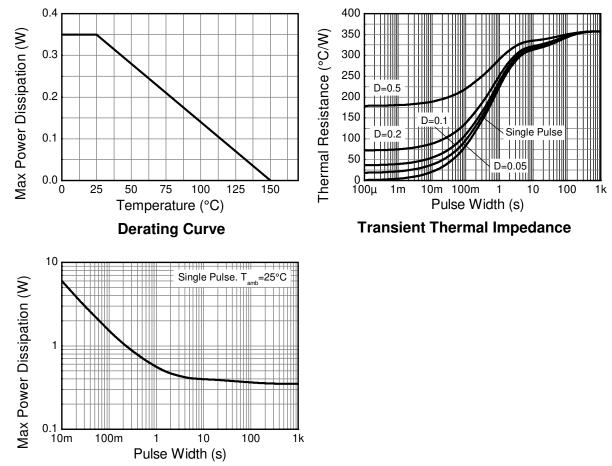
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | ЗA |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

Notes: 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air

To a device included of minimum recommended paragoti for copper that is conditions whilst operating in a steady-state.
Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation

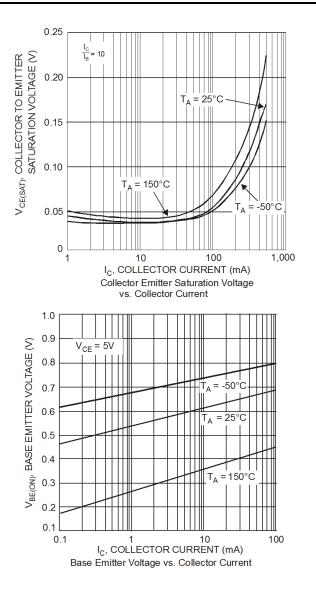
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

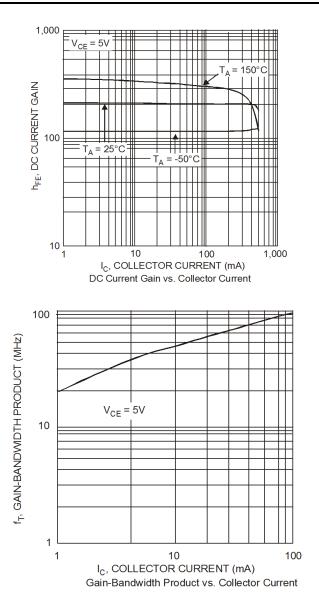
| Characteristic | | | Min | Max | Unit | Test Condition |
|--------------------------------------|--------------------|----------------------|------------|-------|------|---|
| OFF CHARACTERISTICS (Note 10) | | | | | | |
| Collector-Base Breakdown Voltage | MMBTA55 MMBTA56 | BV _{CBO} | -60 -80 | | V | $I_{C} = -100 \mu A, I_{E} = 0$ |
| Collector-Emitter Breakdown Voltage | MMBTA55 MMBTA56 | BV _{CEO} | -60 -80 | — | V | $I_{C} = -1.0 \text{mA}, I_{B} = 0$ |
| Emitter-Base Breakdown Voltage | | BV _{EBO} | -5.0 | -4.0 | | $I_{E} = -100 \mu A, I_{C} = 0$ |
| Collector Cut-Off Current | MMBTA55 MMBTA56 | I _{CBO} | — | -100 | nA | $V_{CB} = -60V, I_E = 0$ $V_{CB} = -80V, I_E = 0$ |
| Collector Cut-Off Current | | ICEX | | -100 | nA | $V_{CE} = -60V, I_{BO} = 0V$ $V_{CE} = -80V, I_{BO} = 0V$ |
| ON CHARACTERISTICS (Note 10) | | | | | | |
| DC Current Gain | | h _{FE} | 100 | _ | _ | $I_{C} = -10mA, V_{CE} = -1.0V$ $I_{C} = -100mA, V_{CE} = -1.0V$ |
| Collector-Emitter Saturation Voltage | | | _ | -0.25 | V | I _C = -100mA, I _B = -10mA |
| Base-Emitter Saturation Voltage | | V _{BE(SAT)} | _ | -1.2 | V | I _C = -100mA, V _{CE} = -1.0V |
| SMALL SIGNAL CHARACTERISTICS | | | | | | |
| Current Gain-Bandwidth Product | | fT | 50 | — | MHz | $V_{CE} = -1.0V, I_C = -100mA, f = 100MHz$ |

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

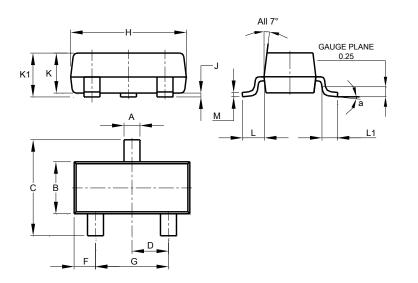






Package Outline Dimensions

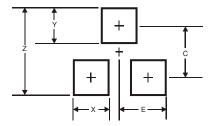
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT23 | | | | | | | |
|-------|----------------------|-------|-------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | |
| С | 2.30 | 2.50 | 2.40 | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | |
| H | 2.80 | 3.00 | 2.90 | | | | |
| J | 0.013 | 0.10 | 0.05 | | | | |
| К | 0.890 | 1.00 | 0.975 | | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | | |
| L | 0.45 | 0.61 | 0.55 | | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | | |
| М | 0.085 | 0.150 | 0.110 | | | | |
| а | | 8° | | | | | |
| All | All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Y | 0.9 |
| С | 2.0 |
| E | 1.35 |



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